# LIGHT COUPLING IN QUANTUM WELL INFRARED PHOTODETECTORS

# JPL

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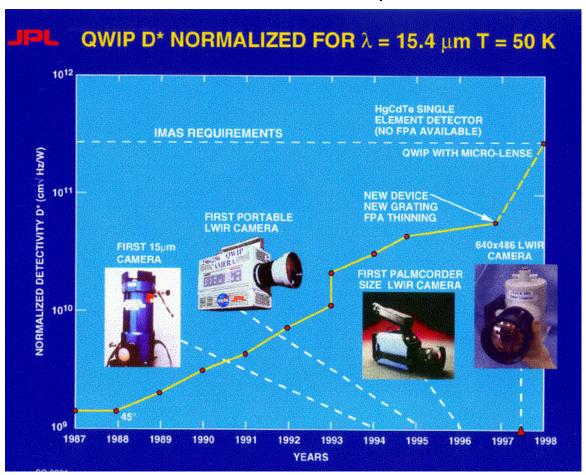
APS/URSI Symposium
Atlanta GA
June 1998





# **Overview**

# Quantum Well Infrared Photodetectors: roadmap



Sarath Gunapala et al., JPL



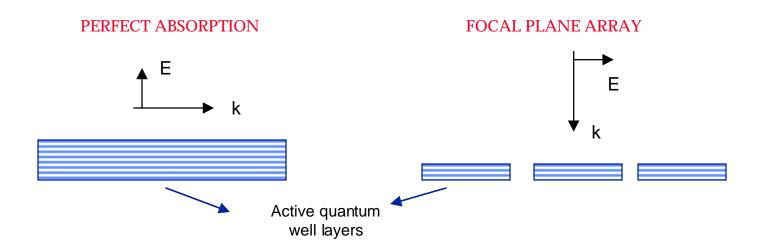


# **Light Coupling and Absorption**

#### **Energy Absorption in QWIPs**

• Electric field must be perpendicular to quantum well layers

 Focal plane arrays require direction of propagation to be perpendicular to quantum well layers



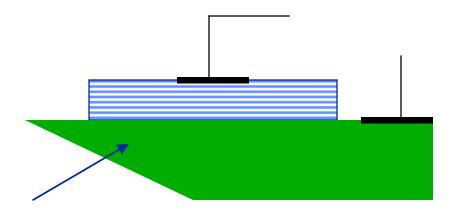


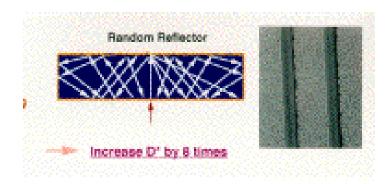


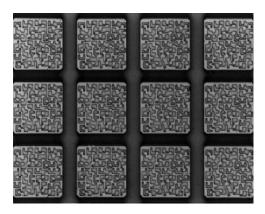
# Historically ...

# Random surface scatterer

# Standard 45 degree edge detector







Expanded corner of 128x128 QWIP focal plane array with 38x38 micron squared pixels.

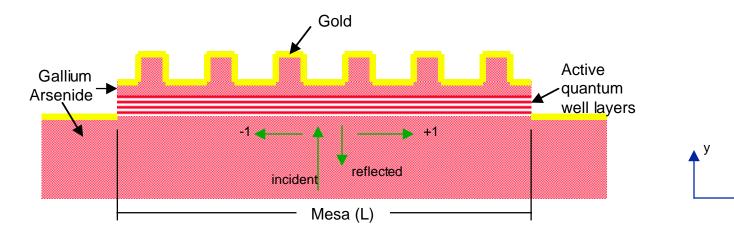




# **Grating Structures**

Grating structures built on mesa to create ±Floquet harmonics

Dark current produced in active quantum well layers



Define Figure of Merit for light coupling; account for dark current by area of region

figure of merit = 
$$\frac{\iint |E_y(x,y)|^2 dxdy}{\sqrt{L}}$$
; integral over active region





#### Coupled Finite Element - Integral Equation Analysis

Apply finite element analysis to each pixel of focal plane array

- Model geometry using finite element mesh
- Truncate mesh using integral equation around boundary
- Apply two-dimensional analysis initially to plane through cross-section of grating

Perform interpolation and differentiation to calculate electric fields

- H-polarization of interest (H in/out of plane; TEy in our geometry)
- Calculate figure of merit over quantum well active region

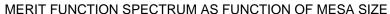
Examine grating geometry, mesa size and effects of microlens

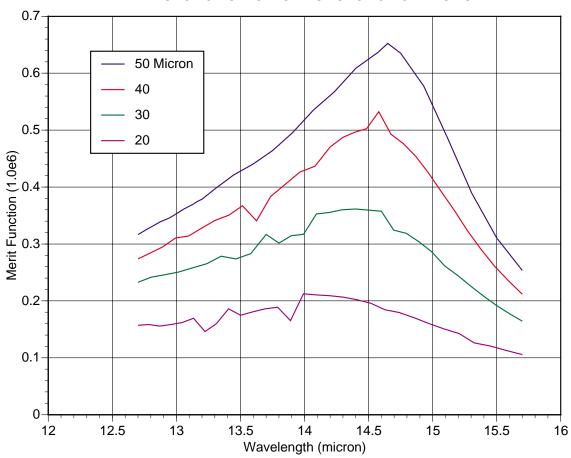
- 1) For optimum grating, compare figure of merit vs. mesa size
- 2) Add microlens to collect 50μ aperture of energy and focus on 20μ mesa
- 3) Examine model for incident field from microlens on mesa structure





# Results for Varying Mesa Width



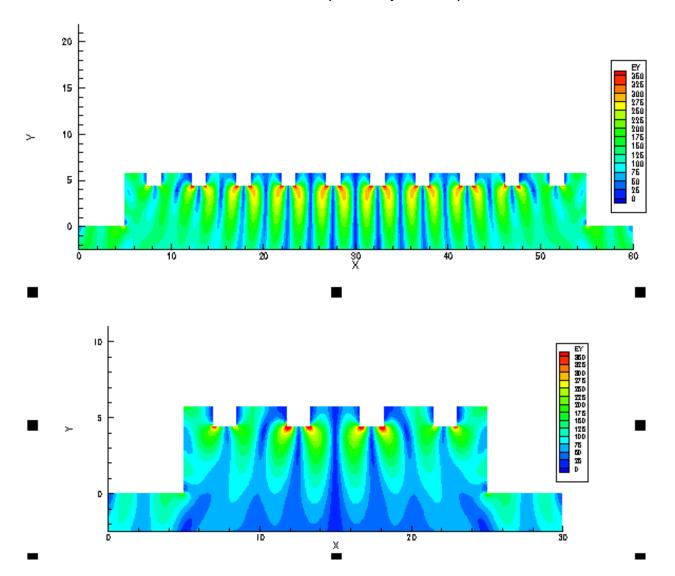






# 50 and 20 Micron Mesa Structures

Electric Field component y; 14.65μm

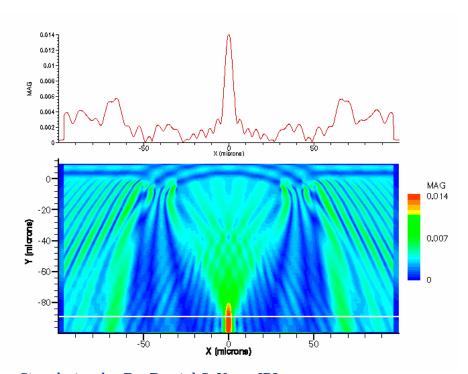


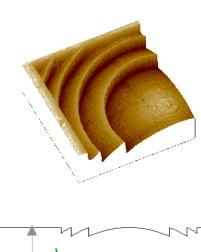


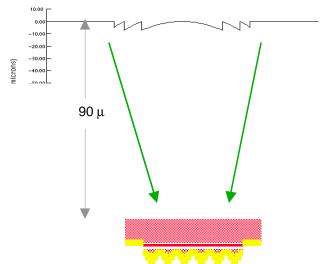


# Can a Microlens Improve Performance

 Maintain collecting area and decrease mesa size reduce dark current







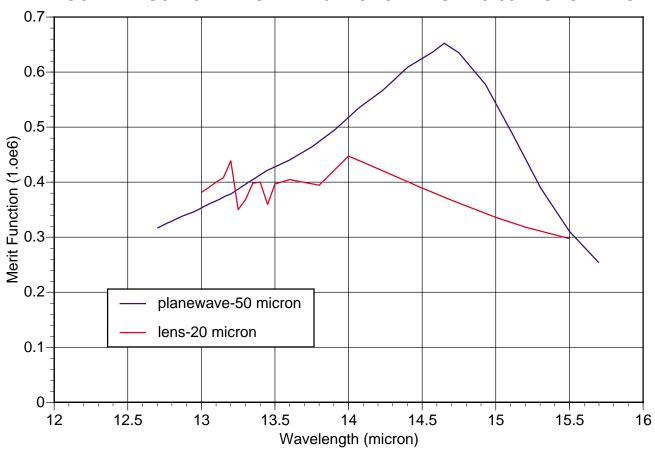
Simulation by Dr. Daniel S. Katz, JPL





# Effect of Lens and Smaller Mesa

#### COMPARISON OF LENS AND 20 MICRON MESA TO 50 MICRON MESA

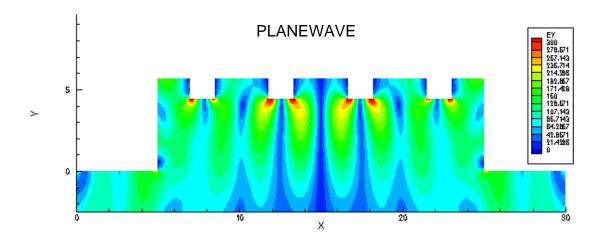


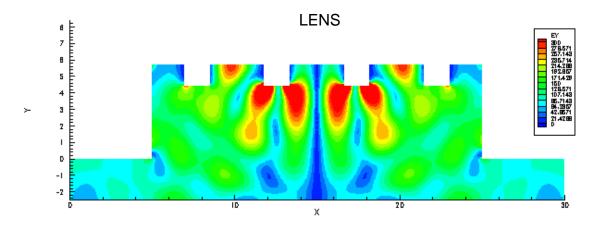




# Planewave and Lens Incidence on 20µ Mesa

Electric Field component y; 14.0μm

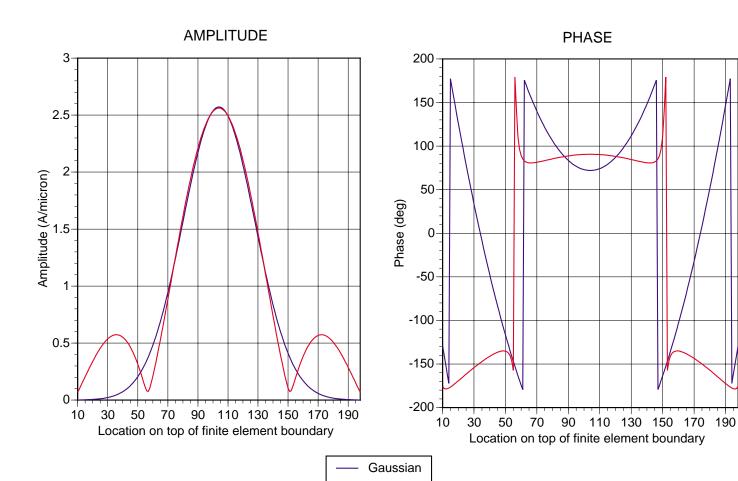








# $\frac{\text{Modeling Field Incident on Mesa Structure}}{\text{Gaussian Model vs. Plane-wave Expansion of Lens field; } 13.0~\mu\text{m}$



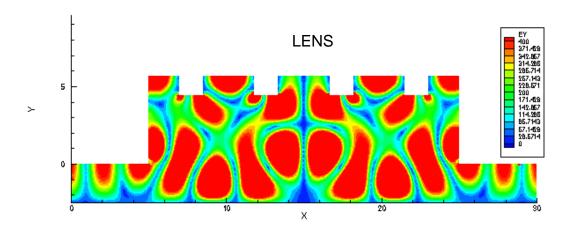
True

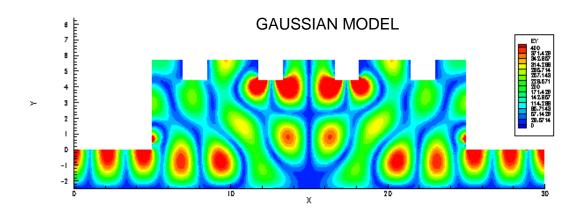




# True Lens Field vs. Gaussian Model

Electric Field component y; 13.0 μm









#### Conclusions

As mesa size decreases, finite grating does not produce first harmonics appropriately

- Savings in dark current are offset by decrease in grating performance
- Grating (periodic surface) does not act as infinite grating

Use of microlens to collect more energy (over 50µm aperture) does not compensate smaller mesa and finite grating size

 Microlens will dump more energy into mesa structure, but cannot compensate smaller grating

Necessary to model microlens accurately when used as incident field on finite element simulation

 Approximate gaussian model does not model phase properly; especially important for periodic grating structure